

868 MHz / 915MHz ISM Band RF Front-End IC

Product Brief

Features

- Integrated High Power PA and Antenna Switch
- +27dBm Psat at 3.3V
- 1.8V to 3.6V Operation
- 1.2dB Rx Bypass Insertion Loss
- For 863-870MHz, and 902-928MHz ISM Bands
- Combined Tx/Rx Port Interface
- Temperature Range: -40°C to +125°C
- 3.0 x 3.0 x 0.55mm 16-pin QFN package
- Die in Wafer Form Available

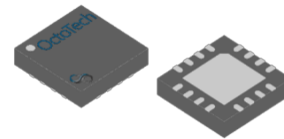
Applications

- IoT (Internet of Things) Nodes, Gateways
- LoRaWAN™, Sigfox, WPAN, LPWAN
- Z-wave®, Weightless™, Wireless M2M
- Smart: Home, City, Lighting, Energy
- Industrial and Building Automation
- Proprietary ISM-Band Wireless Systems

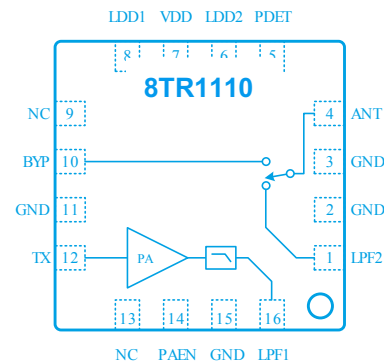
Key Specifications

Description

The 8TR1110 is an integrated RF front-end IC designed for sub-GHz wireless systems including: LoRaWAN™, Sigfox, WPAN, LPWAN, Z-wave®, Weightless™ and other proprietary ISM band wireless systems.



Functional Block Diagram



Tx		BYPASS PATH		CHIP	
Parameter	Typical	Parameter	Typical	Parameter	Typical
Small-Signal Gain	37dB	Rx Insertion Loss	1.2dB	Frequency Range	863-928MHz
Saturated Output Power @ 3.3V	+27dBm	P0.1dB	28dBm	Supply Voltage	1.8 - 3.6V
Output Current @ 3.3V, +27dBm	400mA (35%PAE)	Quiescent Current	0.1uA	Control Voltage (Logic High)	1.2V - Vdd
2 nd /3 rd Harmonics @ +27dBm at ANT	0dBm/MHz			Shutdown Current	0.1uA
Tx-Rx Isolation (Tx Mode)	22dB			Temperature Range	-40 to 125°C